



CHENMKO ENTERPRISE CO.,LTD

Halogens free devices

SURFACE MOUNT

P-Channel Enhancement Mode Field Effect Transistor

VOLTAGE 40 Volts CURRENT 6.3 Ampere

CHM4301ZGP

APPLICATION

- * Servo motor control.
- * Power MOSFET gate drivers.
- * Other switching applications.

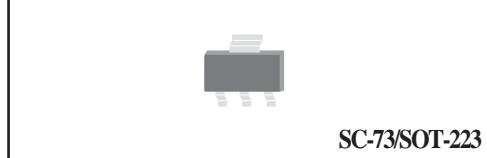
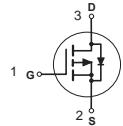
FEATURE

- * Small flat package. (SC-73/SOT-223)
- * High density cell design for extremely low $R_{DS(ON)}$.
- * Rugged and reliable.
- * High saturation current capability.

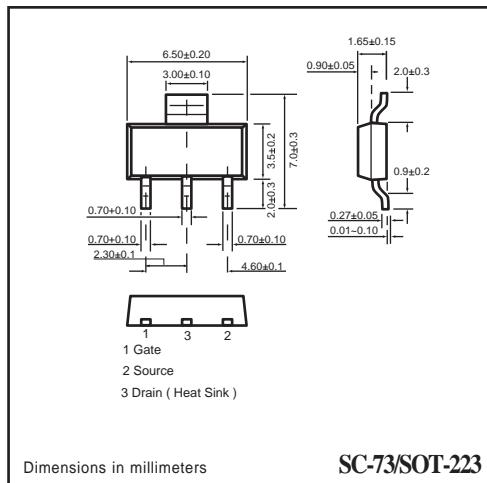
CONSTRUCTION

- * P-Channel Enhancement

CIRCUIT



SC-73/SOT-223



Dimensions in millimeters

SC-73/SOT-223

Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	CHM4301ZGP	Units
V_{DSS}	Drain-Source Voltage	-40	V
V_{GSS}	Gate-Source Voltage	±20	V
I_D	Maximum Drain Current - Continuous	-6.3	A
	- Pulsed (Note 3)	-25	
P_D	Maximum Power Dissipation	3000	mW
T_J	Operating Temperature Range	-55 to 150	°C
T_{STG}	Storage Temperature Range	-55 to 150	°C

Note : 1. Surface Mounted on FR4 Board , $t \leq 10\text{sec}$

2. Pulse Test , Pulse width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

3. Repetitive Rating , Pulse width limited by maximum junction temperature

4. Guaranteed by design , not subject to production testing

Thermal characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1)	42	°C/W
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2008-01

RATING CHARACTERISTIC CURVES (CHM4301ZGP)

Typical Electrical Characteristics

Figure 1. Output Characteristics

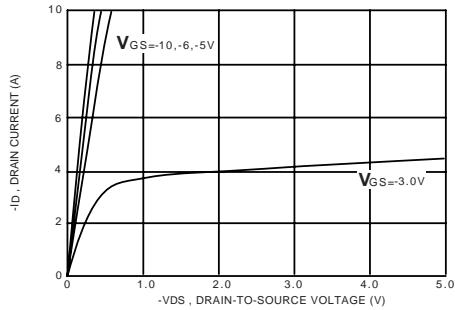


Figure 2. Transfer Characteristics

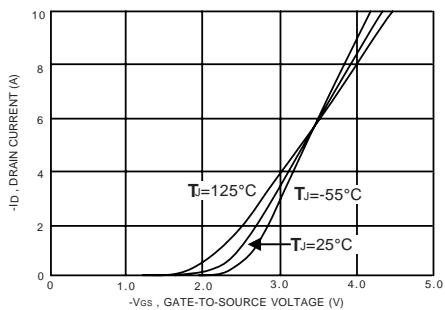


Figure 3. Gate Charge

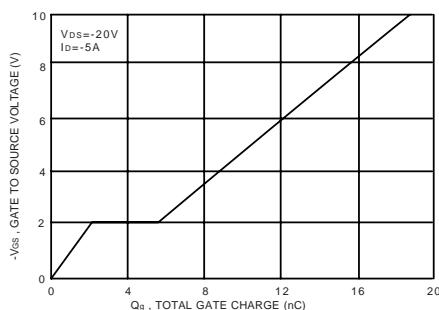


Figure 4. On-Resistance Variation with Temperature

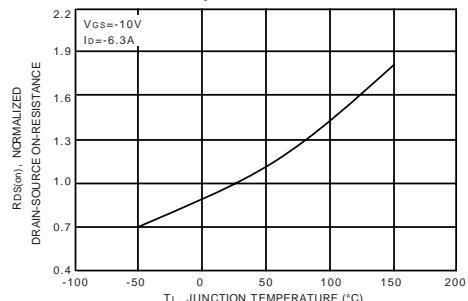


Figure 5. Gate Threshold Variation with Temperature

